**Preferred Device** 

# **Small Signal MOSFET** 250 mAmps, 200 Volts, Logic Level

## N-Channel TO-92

This MOSFET is designed for high voltage, high speed switching applications such as line drivers, relay drivers, CMOS logic, microprocessor or TTL to high voltage interface and high voltage display drivers.

- Low Drive Requirement, V<sub>GS</sub> = 3.0 V max
- Inherent Current Sharing Capability Permits Easy Paralleling of many Devices

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DSS</sub>	200	Vdc
Gate-Source Voltage	VGS	±20	Vdc
Drain Current Continuous (Note 1.) Pulsed (Note 2.)	I <sub>D</sub>	250 500	mAdc
Total Power Dissipation  @ T <sub>A</sub> = 25°C  Derate above T <sub>A</sub> = 25°C	PD	350 6.4	mW mW/°C
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

- 1. The Power Dissipation of the package may result in a lower continuous drain current.
- 2. Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

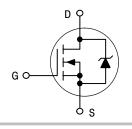


## ON Semiconductor

http://onsemi.com

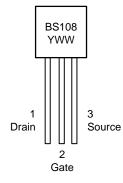
**250 mAMPS 200 VOLTS** RDS(on) = 8  $\Omega$ 

## N-Channel





## **MARKING DIAGRAM & PIN ASSIGNMENT**



= Year WW = Work Week

## **ORDERING INFORMATION**

Device	Package	Shipping	
BS108	TO-92	1000 Units/Box	
BS108ZL1	TO-92	2000 Ammo Pack	

Preferred devices are recommended choices for future use and best overall value.

## $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_{\mbox{\scriptsize A}} = 25^{\circ}\mbox{C unless otherwise noted})$

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					•
Drain–Source Breakdown Voltage (V <sub>GS</sub> = 0, I <sub>D</sub> = 10 μA)	V <sub>(BR)DSS</sub>	200	_	_	Vdc
Zero Gate Voltage Drain Current (V <sub>DSS</sub> = 130 Vdc, V <sub>GS</sub> = 0)	IDSS	_	_	30	nAdc
Gate-Body Leakage Current (V <sub>GS</sub> = 15 Vdc, V <sub>DS</sub> = 0)	IGSSF	_	-	10	nAdc
ON CHARACTERISTICS (2)			•	•	•
Gate Threshold Voltage $(I_D = 1.0 \text{ mA}, V_{DS} = V_{GS})$	VGS(th)	0.5	_	1.5	Vdc
Static Drain-to-Source On-Resistance ( $V_{GS} = 2.0 \text{ Vdc}$ , $I_D = 50 \text{ mA}$ ) ( $V_{GS} = 2.8 \text{ Vdc}$ , $I_D = 100 \text{ mA}$ )	rDS(on)	_ _	_ _	10 8.0	Ohms
Drain Cutoff Current (VGS = 0.2 V, VDS = 70 V)	IDSX	_	-	25	μΑ
DYNAMIC CHARACTERISTICS			•	•	-
Input Capacitance (V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0, f = 1.0 MHz)	C <sub>iss</sub>	_	_	150	pF
Output Capacitance (V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0, f = 1.0 MHz)	C <sub>oss</sub>	_	_	30	pF
Reverse Transfer Capacitance (V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0, f = 1.0 MHz)	C <sub>rss</sub>	_	_	10	pF
SWITCHING CHARACTERISTICS	<u>.                                      </u>		•	•	•
Turn–On Time (See Figure 1)	<sup>t</sup> d(on)	_	_	15	ns
Turn–Off Time (See Figure 1)	t <sub>d</sub> (off)	_	-	15	ns

<sup>2.</sup> Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle = 2.0%.

## **RESISTIVE SWITCHING**

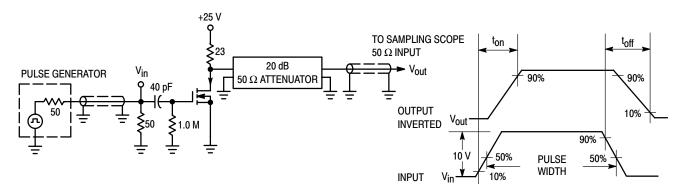
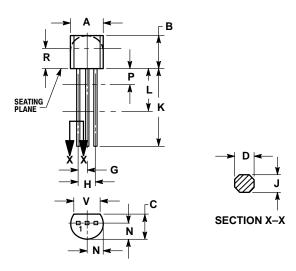


Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

## **PACKAGE DIMENSIONS**

TO-92 CASE 29-11 ISSUE AL



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
  4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0 135		3 43	

STYLE 30:
PIN 1. DRAIN
2. GATE
3. SOURCE

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